

CNX82A  
CNX82AX



**ISOCOM**  
COMPONENTS

**NON-BASE LEAD  
OPTICALLY COUPLED ISOLATOR  
PHOTOTRANSISTOR OUTPUT**



**APPROVALS**

- UL recognised, File No. E91231  
Package System " GG "
- **'X' SPECIFICATION APPROVALS**
- VDE 0884 in 3 available lead form :-  
- STD  
- G form  
- SMD approved to CECC 00802
- Certified to EN60950 by :-  
Nemko - Certificate No. P01102464

**DESCRIPTION**

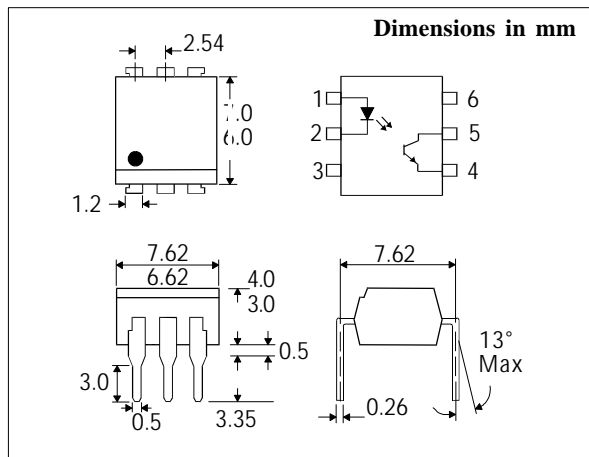
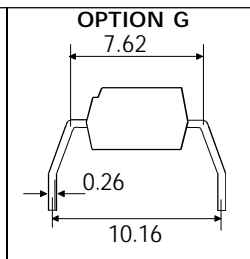
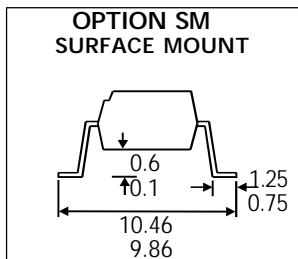
The CNX82A series of optically coupled isolator consists of an infrared light emitting diode and an NPN silicon photo transistor in a standard 6 pin dual in line plastic package with the base pin unconnected.

**FEATURES**

- High Current Transfer Ratio (40% min)
- Low Saturation Voltage suitable for TTL integrated circuits
- High  $BV_{CEO}$  (50V min)
- High Isolation Voltage ( $5.3kV_{RMS}, 7.5kV_{PK}$ )
- Base pin unconnected for improved noise immunity in high EMI environment

**APPLICATIONS**

- DC motor controllers
- Industrial systems controllers
- Signal transmission between systems of different potentials and impedances



**ABSOLUTE MAXIMUM RATINGS  
(25°C unless otherwise specified)**

Storage Temperature \_\_\_\_\_ -55°C to +150°C  
Operating Temperature \_\_\_\_\_ -55°C to +100°C  
Lead Soldering Temperature  
(1/16 inch (1.6mm) from case for 10 secs) 260°C

**INPUT DIODE**

Forward Current \_\_\_\_\_ 60mA  
Reverse Voltage \_\_\_\_\_ 6V  
Power Dissipation \_\_\_\_\_ 105mW

**OUTPUT TRANSISTOR**

Collector-emitter Voltage  $BV_{CEO}$  \_\_\_\_\_ 50V  
Emitter-collector Voltage  $BV_{ECO}$  \_\_\_\_\_ 6V  
Collector Current \_\_\_\_\_ 50mA  
Power Dissipation \_\_\_\_\_ 160mW

**POWER DISSIPATION**

Total Power Dissipation \_\_\_\_\_ 200mW  
(derate linearly 2.67mW/°C above 25°C)

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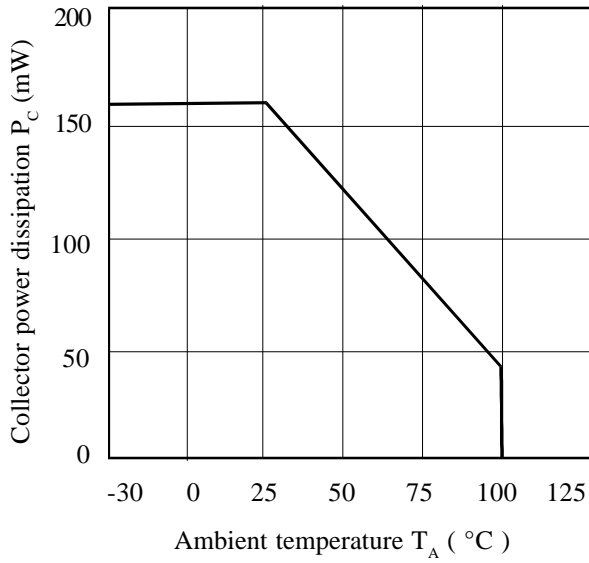
**ELECTRICAL CHARACTERISTICS (  $T_A = 25^\circ\text{C}$  Unless otherwise noted )**

| PARAMETER |                                                          | MIN                | TYP    | MAX | UNITS                          | TEST CONDITION                                                                   |
|-----------|----------------------------------------------------------|--------------------|--------|-----|--------------------------------|----------------------------------------------------------------------------------|
| Input     | Forward Voltage ( $V_F$ )                                |                    | 1.2    | 1.5 | V                              | $I_F = 10\text{mA}$                                                              |
|           | Reverse Current ( $I_R$ )                                |                    |        | 10  | $\mu\text{A}$                  | $V_R = 6\text{V}$                                                                |
| Output    | Collector-emitter Breakdown ( $BV_{CEO}$ )<br>( Note 2 ) | 50                 |        |     | V                              | $I_C = 1\text{mA}$                                                               |
|           | Emitter-collector Breakdown ( $BV_{ECO}$ )               | 6                  |        |     | V                              | $I_E = 100\mu\text{A}$                                                           |
|           | Collector-emitter Dark Current ( $I_{CEO}$ )             |                    |        | 50  | nA                             | $V_{CE} = 10\text{V}$                                                            |
| Coupled   | Current Transfer Ratio ( $I_C / I_F$ )<br>(Note 2)       | 0.4                | 1.5    |     |                                | $10\text{mA } I_F, 0.4\text{V } V_{CE}$<br>$10\text{mA } I_F, 5\text{V } V_{CE}$ |
|           | Collector-emitter Saturation Voltage $V_{CE(SAT)}$       |                    |        | 0.4 | V                              | $10\text{mA } I_F, 4\text{mA } I_C$                                              |
|           | Input to Output Isolation Voltage $V_{ISO}$              | 5300<br>7500       |        |     | $V_{RMS}$<br>$V_{PK}$          | See note 1<br>See note 1                                                         |
|           | Input-output Isolation Resistance $R_{ISO}$              | $5 \times 10^{10}$ |        |     | $\Omega$                       | $V_{IO} = 500\text{V}$ (note 1)                                                  |
|           | Response Time - Rise, tr<br>Response Time - Fall, tf     |                    | 2<br>2 |     | $\mu\text{s}$<br>$\mu\text{s}$ | $V_{CC} = 5\text{V}, I_F = 10\text{mA},$<br>$R_L = 75\Omega$                     |

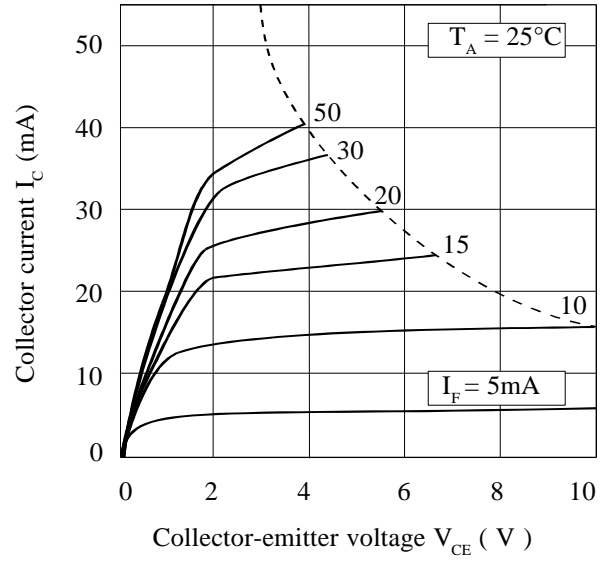
Note 1 Measured with input leads shorted together and output leads shorted together.

Note 2 Special Selections are available on request. Please consult the factory.

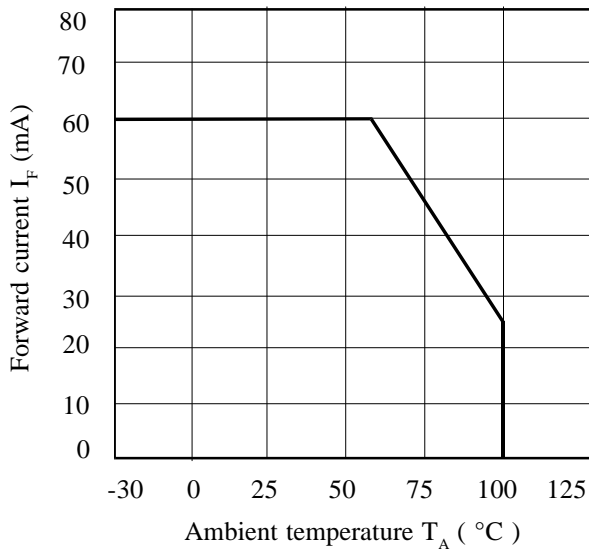
**Collector Power Dissipation vs. Ambient Temperature**



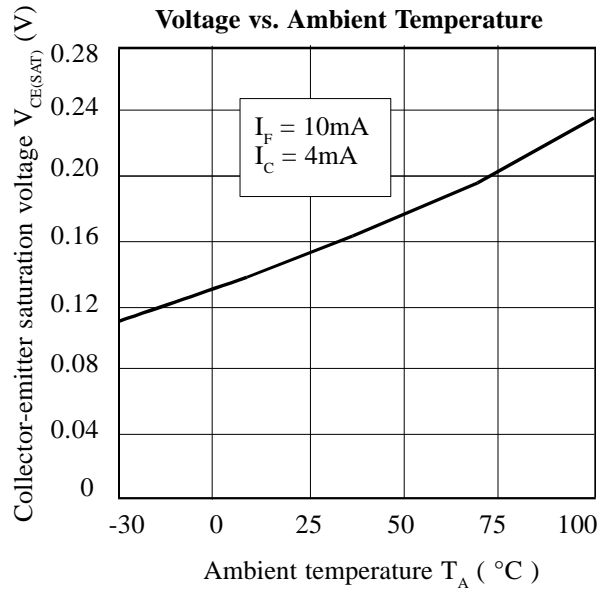
**Collector Current vs. Collector-emitter Voltage**



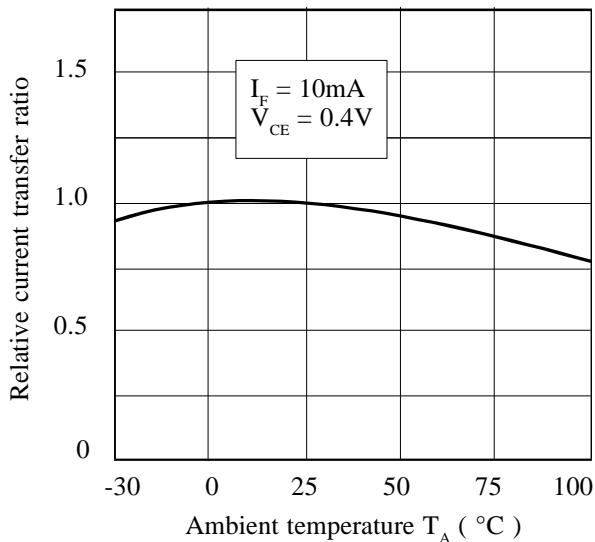
**Forward Current vs. Ambient Temperature**



**Collector-emitter Saturation Voltage vs. Ambient Temperature**



**Relative Current Transfer Ratio vs. Ambient Temperature**



**Relative Current Transfer Ratio vs. Forward Current**

